

## **DATASHEET**

# 1.9mm Round Subminiature" Z-Bend" Lead Phototransistor PT91-21C/TR10



#### **Features**

- Fast response time
- High photo sensitivity
- Small junction capacitance
- Compatible with infrared and vapor phase reflow solder process.
- Pb free
- RoHS Compliance
- The product itself will remain within RoHS compliant version.
- Compliance with EU REACH.
- Compliance Halogen Free .(Br <900 ppm ,Cl <900 ppm , Br+Cl < 1500 ppm)

## Description

- PT91-21C/TR10 is a phototransistor in miniature SMD package which is molded in water clear plastic with spherical top view lens.
- The device is spectrally matched to infrared emitting diode.

## **Applications**

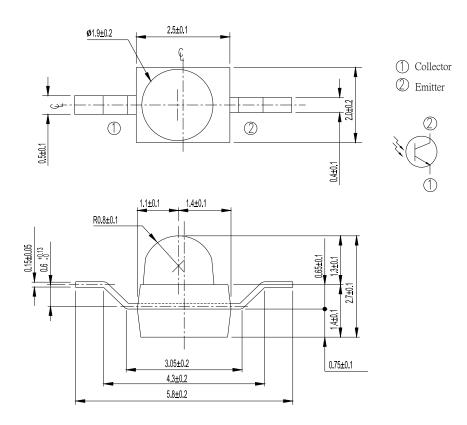
- Miniature switch
- Counters and sorter
- Position sensor
- Infrared applied system

#### **Device Selection Guide**

Device No.	Chip Material	Lens Color	
PT91-21C/TR10	Silicon	Water clear	



# **Package Dimensions**



Notes: 1.All dimensions are in millimeters

2.Tolerances unless dimensions ±0.1mm



**Absolute Maximum Ratings (Ta=25℃)** 

Parameter	Symbol	Rating	Units
Collector Emitter Voltage	$V_{CEO}$	30	V
Emitter Collector Voltage	$V_{ECO}$	5	V
Collector Current	I <sub>C</sub>	20	mA
Operating Temperature	T <sub>opr</sub>	-25 ~ +85	$^{\circ}\mathbb{C}$
Storage Temperature	T <sub>stg</sub>	-40 ~ +100	$^{\circ}$ C
Soldering Temperature *1	T <sub>sol</sub>	260	$^{\circ}\mathbb{C}$
Power Dissipation at (or below) 25°C Free Air Temperature	Pc	75	mW

**Notes:** \*1:Soldering time ≤ 5 seconds.

## **Electro-Optical Characteristics (Ta=25°C)**

Parameter	Symbol	Min.	Тур.	Max.	Units	Condition
Rang of Spectral Bandwidth	λ <sub>0.5</sub>	400		1100	nm	
Wavelength of Peak Sensitivity	$\lambda_{P}$		940		nm	
Collector Emitter Breakdown Voltage	BV <sub>CEO</sub>	30			V	I <sub>C</sub> =100μA Ee=0mW/cm <sup>2</sup>
Emitter Collector Breakdown Voltage	BV <sub>ECO</sub>	5			V	I <sub>E</sub> =100μA Ee=0mW/cm <sup>2</sup>
Collecto Emitter Saturation Voltage	V <sub>CE(sat)</sub>			0.4	٧	I <sub>C</sub> =2mA Ee=1m W/cm <sup>2</sup>
Collector Dark Current	I <sub>CEO</sub>			100	nA	$V_{CE}$ =20V Ee=0mW/cm <sup>2</sup>
On State Collector Current	I <sub>C(ON)</sub>	1.0	1.5		mA	V <sub>CE</sub> =5V Ee=1mW /cm²
Rise Time	t <sub>r</sub>		15		110	V <sub>CE</sub> =5V I <sub>C</sub> =1mA
Fall Time	t <sub>f</sub>		15		μS	$R_L=1000\Omega$

**Intensity Specifications for Bin Grading** 

Rank	Test Condition	Min	Max	Units
Bin1	Ee=1mW/cm <sup>2</sup> V <sub>CE</sub> =5V	1.0	2.0	
Bin2		1.5	3.0	
Bin3		2.0	4.0	mA
Bin4		2.5	5.0	
Bin5		3.0	6.0	



## **Typical Electrical/Optical/Characteristics Curves**

Fig.1 Collector Power Dissipation vs. Ambient Temperature

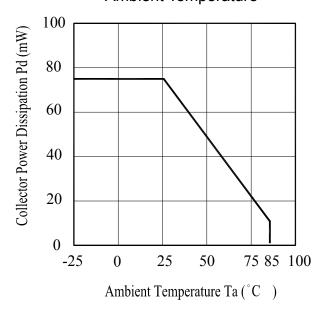


Fig.3 Relative Collector Current vs. Ambient Temperature

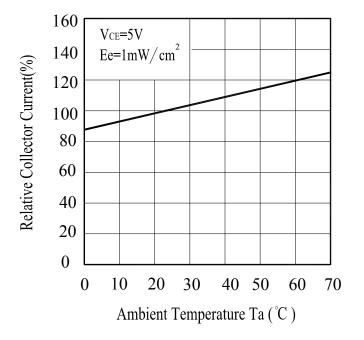


Fig.2 Spectral Sensitivity

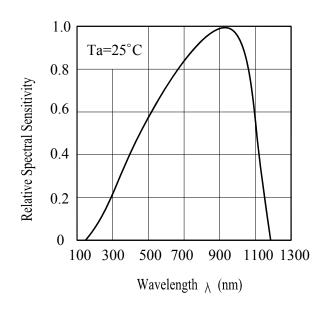
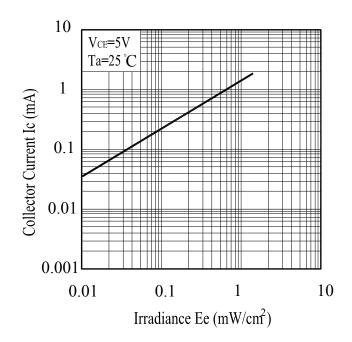


Fig.4 Collector Current vs. Irradiance





## **Typical Electro-Optical Characteristics Curves**

Fig.5 Collector Dark Current vs.
Ambient Temperature

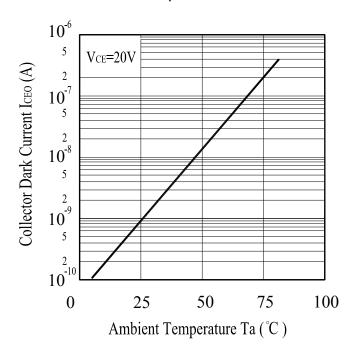
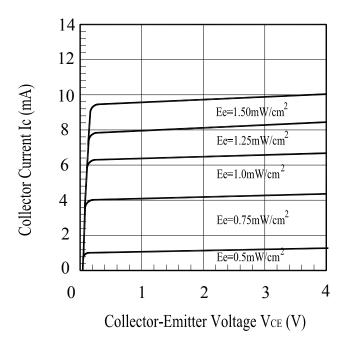


Fig.6 Collector Current vs.
Collector-Emitter Voltage





#### **Precautions For Use**

#### 1. Over-current-proof

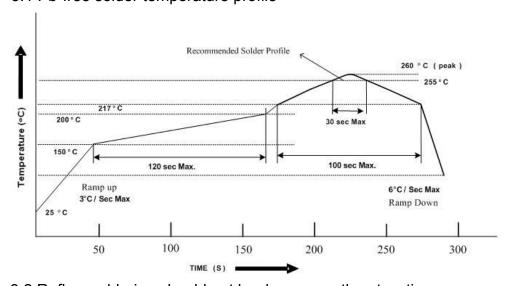
Customer must apply resistors for protection, otherwise slight voltage shift will cause big current change (Burn out will happen).

#### 2. Storage

- 2.1 Do not open moisture proof bag before the products are ready to use.
- 2.2 Before opening the package, the Phototransistor should be kept at 10°C~30°C and 90%RH or less.
- 2.3 The Phototransistor suggested be used within one year.
- 2.4 After opening the package, the devices must be stored at 10°C~30°C and ≤ 60%RH, and used within 168 hours (floor life). If unused Phototransistor remain, it should be stored in moisture proof packages.
- 2.5 If the moisture absorbent material (desiccant material) has faded or unopened bag has exceeded the shelf life or devices (out of bag) have exceeded the floor life, baking treatment is required.
- 2.6 If baking is required, refer to IPC/JEDEC J-STD-033 for bake procedure or recommend the following conditions:
  - 96 hours at 60°C ± 5°C and < 5 % RH (reeled/tubed/loose units)

#### 3. Soldering Condition

3.1 Pb-free solder temperature profile



- 3.2 Reflow soldering should not be done more than two times.
- 3.3 When soldering, do not put stress on the Phototransistor during heating.
- 3.4 After soldering, do not warp the circuit board.

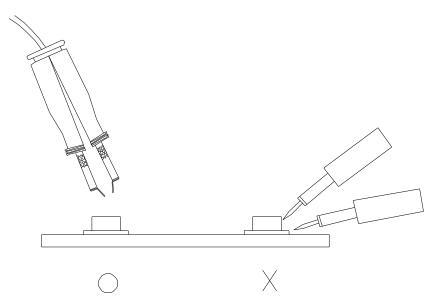


#### Soldering Iron

Each terminal is to go to the tip of soldering iron temperature less than 350°C for 3 seconds within once in less than the soldering iron capacity 25W. Leave two seconds and more intervals, and do soldering of each terminal. Be careful because the damage of the product is often started at the time of the hand solder.

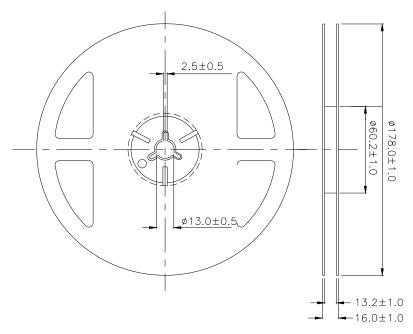
#### 5. Repairing

Repair should not be done after the Phototransistor have been soldered. When repairing is unavoidable, a double-head soldering iron should be used (as below figure). It should be confirmed beforehand whether the characteristics of the Phototransistor will or will not be damaged by repairing.



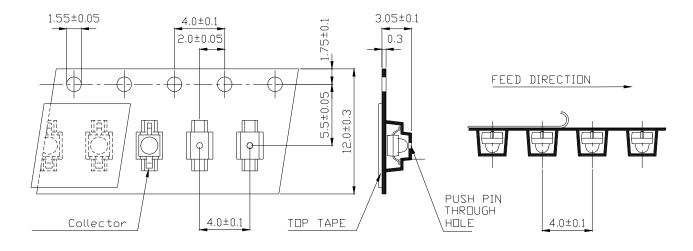


## **Package Dimensions**



**Note:** The tolerances unless mentioned are ±0.1, Unit: mm.

## **Carrier Taping Dimensions: (Quantity: 1000PCS/Reel)**



**Note:** The tolerances unless mentioned are ±0.1, Unit: mm.



**Label Form Specification** 



CPN: Customer's Production Number

P/N : Production Number QTY: Packing Quantity

CAT: Ranks

**HUE: Peak Wavelength** 

REF: Reference

LOT No: Lot Number

#### **DISCLAIMER**

- 1. EVERLIGHT reserves the right(s) on the adjustment of product material mix for the specification.
- The product meets EVERLIGHT published specification for a period of twelve (12) months from date of shipment.
- 3. The graphs shown in this datasheet are representing typical data only and do not show guaranteed values.
- 4. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from the use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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